

FQPF7N65CYDTU

FQPF7N65CYDTU Information



E-mail: salesdept@heisener.com

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



FQPF7N65CYDTU Specifications

Manufacturer Part Number	FQPF7N65CYDTU
Manufacturer	Fairchild/ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3 Full Pack, Formed Leads
Series	QFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	7A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	36nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1245pF @ 25V
Vgs (Max)	$\pm 30 V$
FET Feature	-
Power Dissipation (Max)	52W (Tc)
Rds On (Max) @ Id, Vgs	1.4 Ohm @ 3.5A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220F-3 (Y-Forming)
Package / Case	TO-220-3 Full Pack, Formed Leads
	Report errors?

FQPF7N65CYDTU Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE GUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

FQPF7N65CYDTU Payment Methods





If you have any question about FQPF7N65CYDTU, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com